OMRON

MOS FET Relays

G3VM-353A/D

Analog-switching MOS FET Relay with SPST-NC (Single-pole, Single-throw, **Normally Closed) Contacts**

- Switches minute analog signals.
- Switching AC and DC.

■ Application Examples

- Electronic automatic exchange systems
- · Security systems
- Datacom (modem) systems
- FA systems
- Measurement devices



Note: The actual product is marked differently from the image

shown here.

■List of Models

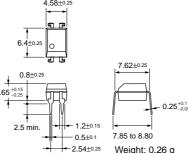
Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NC	PCB terminals	350 VAC	G3VM-353A	100	
	Surface-mounting		G3VM-353D		
	terminals		G3VM-353D(TR)		1,500

■ Dimensions

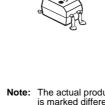
Note: All units are in millimeters unless otherwise indicated.



Note: The actual product is marked differently from the image shown here.

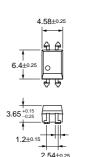


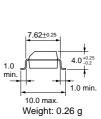
Weight: 0.26 g



G3VM-353D

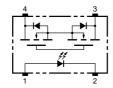
The actual product is marked differently from the image shown here.



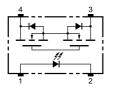


■ Terminal Arrangement/Internal Connections (Top View)

G3VM-353A

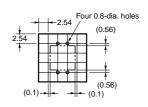


G3VM-353D



■ PCB Dimensions (Bottom View)

G3VM-353A



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-353D



Note:

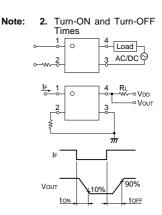
■ Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Rating	Unit	Measurement Conditions	
Input	LED forward current	I _F	50	mA		
	Repetitive peak LED forward current	I _{FP}	1	Α	100 μs pulses, 100 pps	
	LED forward current reduction rate	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C	
	LED reverse voltage	V _R	5	V		
	Connection temperature	Tj	125	°C		
Output	Output dielectric strength	V _{OFF}	350	V		
	Continuous load current	Io	150	mA		
	ON current reduction rate	Δ I _{ON} /°C	-1.5	mA/°C	Ta ≥ 25°C	
	Connection temperature	Tj	125	°C		
	ic strength between input and See note 1.)	V _{I-O}	2,500	Vrms	AC for 1 min	
Operating temperature		Ta	-40 to +85	°C	With no icing or condensatio	
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation	
Solderin	Soldering temperature (10 s)		260	°C	10 s	

 The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	V _F	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	I _R			10	μА	V _R = 5 V
	Capacity between termi- nals	C _T		30		pF	V = 0, f = 1 MHz
	Trigger LED forward cur- rent	I _{FT}		1	3	mA	I _{OFF} = 10 μA
Output	Maximum resistance with output ON	R _{ON}		15	25	Ω	I _O = 150 mA
	Current leakage when the relay is open	I _{LEAK}			1.0	μА	I _F = 5 mA, V _{OFF} = 350 V
Capacity between I/O terminals		C _{I-O}		0.8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000			ΜΩ	V_{I-O} = 500 VDC, RoH \leq 60%
Turn-ON time		tON		0.1	1.0	ms	I_F = 5 mA, R_L = 200 $Ω$,
Turn-OFF time		tOFF		1.0	3.0	ms	V _{DD} = 20 V (See note 2.)



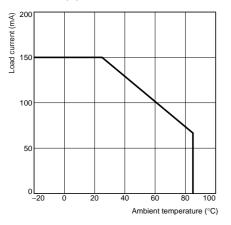
■Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			280	V
Operating LED forward current	IF	5		25	mA
Continuous load current	Io			150	mA
Operating temperature	Ta	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-353A(D)



■ Safety Precautions

Refer to page 6 for precautions common to all G3VM models.